

Features

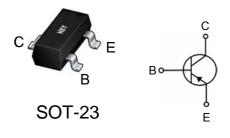
Collector Current: I_C= -0.1A

• Power Dissipation of 200mw

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)	
BC857CLT1G	SOT-23	3x	3000	





Maxmim Ratings (Ta=25 unless otherwise noted)

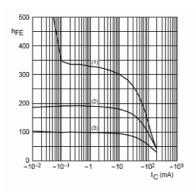
Symbl	Parameter	Value	Unit
Vсво	Collector-Base Voltage	-50	V
VCEO	Collector-Emitter Voltage	-45	V
VEBO	Emitter-Base Voltage	-5	V
Ic	Collector Current-Continuous	-01	Α
Pc	Collector Power Dissipation	200	mW
Tj	Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature	-55-150	$^{\circ}$



Electrcal Charcteristics (Ta=25 unless otherwise specified)

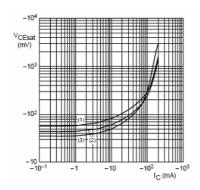
Symbol	Test conditions	Min	Max	Unit
VCBO	IC= -10μA, IE=0	-50		V
nitter breakdown voltage		-45		٧
VEBO	IE= -1μΑ, IC=0	-5		V
ICBO	VCB=-45 V,IE=0		-0.1	μΑ
ICEO	VCE=-40 V,IB=0		-0.1	μΑ
IEBO	VEB= -5 V , IC=0		-0.1	μΑ
hFE	VCE= -5V, IC= -2mA	420	800	
VCE(sat)	IC=-100mA, IB= -5 mA		-0.5	>
VBE(sat)	IC= -100mA, IB= -5mA		-1.1	V
fT	VCE= -5 V, IC= -10mA	100		MHz
	f=100MHz			IVIIIZ
Cob	VCB=-10V, f=1MHz		4.5	pF
	VCBO VCEO VEBO ICBO ICEO IEBO hFE VCE(sat) VBE(sat)	VCBO IC= -10μA, IE=0 VCEO IC= -10mA, IB=0 VEBO IE= -1μA, IC=0 ICBO VCB=-45 V,IE=0 ICEO VCE=-40 V,IB=0 IEBO VEB= -5 V, IC=0 hFE VCE= -5V, IC= -2mA VCE(sat) IC=-100mA, IB= -5 mA VBE(sat) IC= -100mA, IB= -5mA fT VCE= -5 V, IC= -10mA f=100MHz	VCBO IC= -10μA, IE=0 -50 VCEO IC= -10mA, IB=0 -45 VEBO IE= -1μA, IC=0 -5 ICBO VCB=-45 V,IE=0 ICEO VCE=-40 V,IB=0 IEBO VEB= -5 V, IC=0 hFE VCE= -5V, IC= -2mA 420 VCE(sat) IC=-100mA, IB= -5 mA VBE(sat) IC= -100mA, IB= -5mA fT VCE= -5 V, IC= -10mA 100 f=100MHz	VCBO IC= -10μA, IE=0 -50 VCEO IC= -10mA, IB=0 -45 VEBO IE= -1μA, IC=0 -5 ICBO VCB=-45 V,IE=0 -0.1 ICEO VCE=-40 V,IB=0 -0.1 IEBO VEB= -5 V, IC=0 -0.1 hFE VCE= -5V, IC= -2mA 420 800 VCE(sat) IC=-100mA, IB= -5 mA -0.5 VBE(sat) IC= -100mA, IB= -5mA -1.1 fT VCE= -5 V, IC= -10mA 100 f=100MHz 100 100

Typical Characteristics



BC857A; V_{CE} = -5 V. (1) T_{amb} = 150 °C. (2) T_{amb} = 25 °C. (3) T_{amb} = -55 °C.

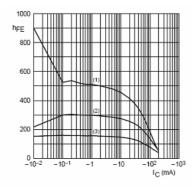
Fig.2 DC current gain as a function of collector current; typical values.



BC857A; I_C/I_B = 20. (1) T_{amb} = 150 °C. (2) T_{amb} = 25 °C.

(3) T_{amb} = −55 °C.

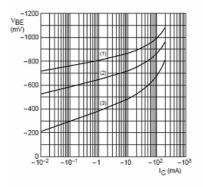
Fig.4 Collector-emitter saturation voltage as a function of collector current; typical values



BC857B; V_{CE} = -5 V. (1) T_{amb} = 150 °C. (2) T_{amb} = 25 °C.

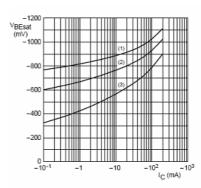
(3) T_{amb} = -55 °C.

Fig.6 DC current gain as a function of collector current; typical values.



BC857A; V_{CE} = -5 V. (1) T_{amb} = -55 °C. (2) T_{amb} = 25 °C. (3) T_{amb} = 150 °C.

Fig.3 Base-emitter voltage as a function of collector current; typical values.

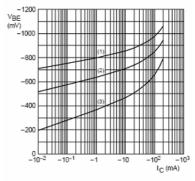


BC857A; I_C/I_B = 20.

(1) T_{amb} = -55 °C. (2) T_{amb} = 25 °C.

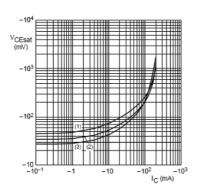
(3) T_{amb} = 150 °C.

Fig.5 Base-emitter saturation voltage as a function of collector current; typical values.



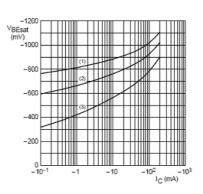
BC857B; V_{CE} = -5 V. (1) T_{amb} = -55 °C. (2) T_{amb} = 25 °C. (3) T_{amb} = 150 °C.

Fig.7 Base-emitter voltage as a function of collector current; typical values.



BC857B; I_C/I_B = 20. (1) T_{amb} = 150 °C. (2) T_{amb} = 25 °C. (3) T_{amb} = -55 °C.

Fig.8 Collector-emitter saturation voltage as a function of collector current; typical values.

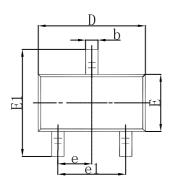


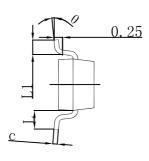
- BC857B; I_O/I_B = 20. (1) T_{amb} = -55 °C. (2) T_{amb} = 25 °C. (3) T_{amb} = 150 °C.

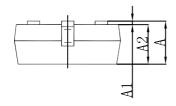
Fig.9 Base-emitter saturation voltage as a function of collector current; typical values.

Package Dimensions

SOT-23

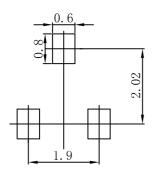






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

Suggested Pad Layout



- Note:
 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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